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Kind regards,

Team Nexperia

PDTC124X series

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

Rev. 07 — 16 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

Type number	Package			PNP complement
	NXP	JEITA	JEDEC	
PDTC124XE	SOT416	SC-75	-	PDTA124XE
PDTC124XEF	SOT490	SC-89	-	PDTA124XEF
PDTC124XK	SOT346	SC-59A	TO-236	PDTA124XK
PDTC124XM	SOT883	SC-101	-	PDTA124XM
PDTC124XS ^[1]	SOT54	SC-43A	TO-92	PDTA124XS
PDTC124XT	SOT23	-	TO-236AB	PDTA124XT
PDTC124XU	SOT323	SC-70	-	PDTA124XU

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- General-purpose switching and amplification
- Inverter and interface circuits

Circuit drivers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	



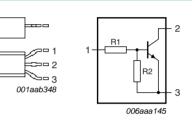
2. Pinning information

Table 3. Pinning

	<u> </u>	
Pin	Description	Simplified outline Symbol
SOT54		
1	input (base)	
2	output (collector)	2
3	GND (emitter)	001aab347 R1 R2

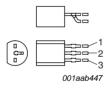
CO	TE	4 A
50	10	4A

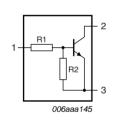
1	input (base)
2	output (collector)
3	GND (emitter)



SOT54 variant

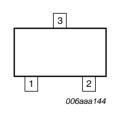
1	input (base)
2	output (collector)
3	GND (emitter)

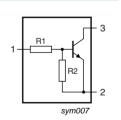




SOT23; SOT323; SOT346; SOT416; SOT490

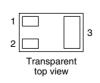
1	input (base)
2	GND (emitter)
3	output (collector)

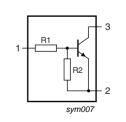




SOT883

1	input (base)
2	GND (emitter)
3	output (collector)





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NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

3. **Ordering information**

Table 4. **Ordering information**

PDTC124XE SC-75 plastic surface mounted package; 3 leads SOT45 PDTC124XEF SC-89 plastic surface mounted package; 3 leads SOT45 PDTC124XK SC-59A plastic surface mounted package; 3 leads SOT34 PDTC124XM SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm	ype number	Package					
PDTC124XEF SC-89 plastic surface mounted package; 3 leads SOT49 PDTC124XK SC-59A plastic surface mounted package; 3 leads SOT34 PDTC124XM SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm PDTC124XS[1] SC-43A plastic single-ended leaded (through hole) package; SOT54		Name	Description	Version			
PDTC124XK SC-59A plastic surface mounted package; 3 leads SOT34 PDTC124XM SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm PDTC124XS[1] SC-43A plastic single-ended leaded (through hole) package; SOT54	DTC124XE	SC-75	plastic surface mounted package; 3 leads	SOT416			
PDTC124XM SC-101 leadless ultra small plastic package; 3 solder lands; SOT86 body 1.0 × 0.6 × 0.5 mm PDTC124XS[1] SC-43A plastic single-ended leaded (through hole) package; SOT54	DTC124XEF	SC-89	plastic surface mounted package; 3 leads	SOT490			
$ body \ 1.0 \times 0.6 \times 0.5 \ mm $ PDTC124XS[1] SC-43A plastic single-ended leaded (through hole) package; SOT54	DTC124XK	SC-59A	plastic surface mounted package; 3 leads	SOT346			
places of partial places of partial pa	DTC124XM	SC-101		SOT883			
	DTC124XS[1]	SC-43A		SOT54			
PDTC124XT - plastic surface mounted package; 3 leads SOT23	DTC124XT	-	plastic surface mounted package; 3 leads	SOT23			
PDTC124XU SC-70 plastic surface mounted package; 3 leads SOT32	DTC124XU	SC-70	plastic surface mounted package; 3 leads	SOT323			

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

Marking 4.

Product data sheet

Table 5. **Marking codes**

3	
Type number	Marking code ^[1]
PDTC124XE	32
PDTC124XEF	32
PDTC124XK	51
PDTC124XM	DZ
PDTC124XS	TC124X
PDTC124XT	*46
PDTC124XU	*51

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V_{EBO}	emitter-base voltage	open collector		-	7	V
VI	input voltage					
	positive			-	+40	V
	negative			-	-7	V
Io	output current			-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$				
	SOT416		[1]	-	150	mW
	SOT490		[1][2]	-	250	mW
	SOT346		<u>[1]</u>	-	250	mW
	SOT883		[2][3]	-	250	mW
	SOT54		[1]	-	500	mW
	SOT23		<u>[1]</u>	-	250	mW
	SOT323		<u>[1]</u>	-	200	mW
T _{stg}	storage temperature			- 65	+150	°C
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> -	-	833	K/W
	SOT490		[1][2] -	-	500	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> -	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

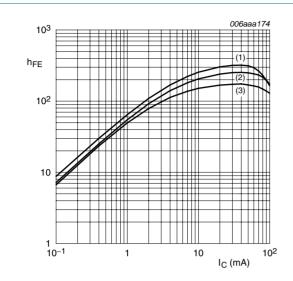
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

u	<u> </u>					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	120	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	80	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	-	8.0	0.5	٧
V _{I(on)}	on-state input voltage	V_{CE} = 300 mV; I_{C} = 2 mA	2	1.1	-	٧
R1	bias resistor 1 (input)		15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		1.7	2.1	2.6	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.



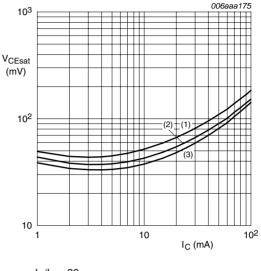
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 1. DC current gain as a function of collector current; typical values



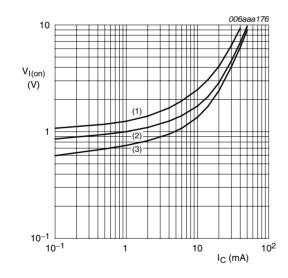
$$I_C/I_B = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



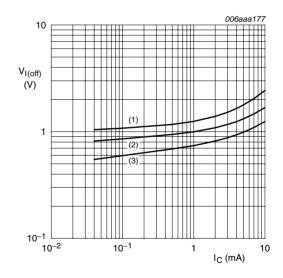
$$V_{CE} = 0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

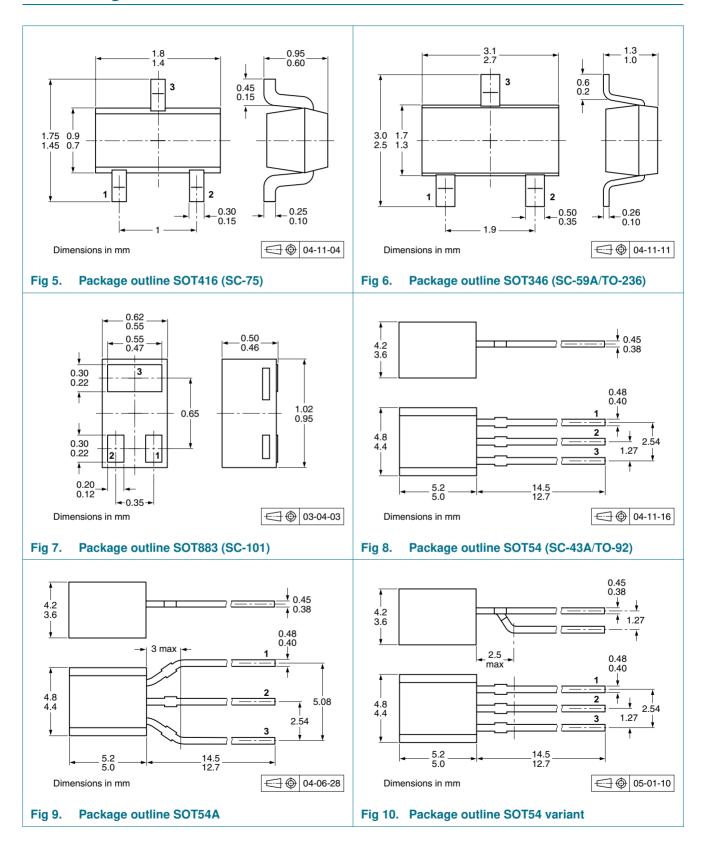
(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 4. Off-state input voltage as a function of collector current; typical values

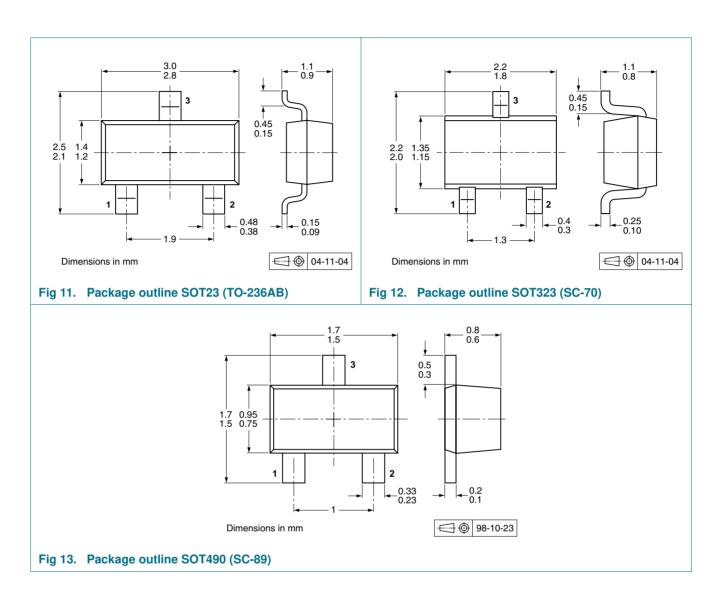
8. Package outline



Product data sheet

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NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω



Product data sheet

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NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

Packing information 9.

Packing methods Table 9.

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Package	Description	Packing quantity			
		3000	4000	5000	10000
SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
SOT490	4 mm pitch, 8 mm tape and reel	-	-115	-	-
SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
SOT883	2 mm pitch, 8 mm tape and reel	-	-	-	-315
SOT54	bulk, straight leads	-	-	-412	-
SOT54A	tape and reel, wide pitch	-	-	-	-116
	tape ammopack, wide pitch	-	-	-	-126
SOT54 variant	bulk, delta pinning	-	-	-112	-
SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-	-235
SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-	-135
	SOT416 SOT490 SOT346 SOT883 SOT54 SOT54A	SOT416 4 mm pitch, 8 mm tape and reel SOT490 4 mm pitch, 8 mm tape and reel SOT346 4 mm pitch, 8 mm tape and reel SOT883 2 mm pitch, 8 mm tape and reel SOT54 bulk, straight leads SOT54A tape and reel, wide pitch tape ammopack, wide pitch SOT54 variant bulk, delta pinning SOT23 4 mm pitch, 8 mm tape and reel	3000 SOT416 4 mm pitch, 8 mm tape and reel -115 SOT490 4 mm pitch, 8 mm tape and reel - SOT346 4 mm pitch, 8 mm tape and reel -115 SOT883 2 mm pitch, 8 mm tape and reel - SOT54 bulk, straight leads - SOT54A tape and reel, wide pitch - tape ammopack, wide pitch - SOT54 variant bulk, delta pinning - SOT23 4 mm pitch, 8 mm tape and reel -215	3000 4000 SOT416 4 mm pitch, 8 mm tape and reel -115 - SOT490 4 mm pitch, 8 mm tape and reel - -115 SOT346 4 mm pitch, 8 mm tape and reel -115 - SOT883 2 mm pitch, 8 mm tape and reel - - SOT54 bulk, straight leads - - SOT54A tape and reel, wide pitch - - tape ammopack, wide pitch - - SOT54 variant bulk, delta pinning - - SOT23 4 mm pitch, 8 mm tape and reel -215 -	3000 4000 5000 SOT416 4 mm pitch, 8 mm tape and reel -115 - - SOT490 4 mm pitch, 8 mm tape and reel - -115 - SOT346 4 mm pitch, 8 mm tape and reel -115 - - SOT883 2 mm pitch, 8 mm tape and reel - - - - SOT54 bulk, straight leads - - -412 SOT54A tape and reel, wide pitch - - - tape ammopack, wide pitch - - - SOT54 variant bulk, delta pinning - - -112 SOT23 4 mm pitch, 8 mm tape and reel -215 - -

^[1] For further information and the availability of packing methods, see Section 12.

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NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

10. Revision history

Table 10. Revision history

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC124X_SER_7	20091116	Product data sheet	-	PDTC124X_SER_6
Modifications:		et was changed to reflect the legal definitions and disclair		
PDTC124X_SER_6	20050714	Product data sheet	-	PDTC124X_SERIES_5
PDTC124X_SERIES_5	20040813	Product specification	-	PDTC124X_SERIES_4
PDTC124X_SERIES_4	20030410	Product specification	-	PDTC124XEF_2 PDTC124XE_3
PDTC124XE_3	19990518	Product specification	-	PDTC124XE_2
PDTC124XE_2	19980921	Product specification	-	PDTC124XE_1
PDTC124XE_1	19971215	Product specification	-	-
PDTC124XEF_2	19990518	Preliminary specification	-	PDTC124XEF_1
PDTC124XEF_1	19981111	Preliminary specification	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTC124X series

NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

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